

## KSC2690/2690A

## Audio Frequency High Frequency Power Amplifier

Complement to KSA1220/KSA1220A



## **NPN Epitaxial Silicon Transistor**

### Absolute Maximum Ratings T<sub>C</sub>=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V <sub>CBO</sub>	Collector-Base Voltage		
	: KSC2690	120	V
	: KSC2690A	160	V
V <sub>CEO</sub>	Collector- Emitter Voltage		
	: KSC2690	120	V
	: KSC2690A	160	V
V <sub>EBO</sub>	Emitter-Base Voltage	5	V
I <sub>C</sub>	Collector Current (DC)	1.2	Α
I <sub>CP</sub>	*Collector Current (Pulse)	2.5	Α
l <sub>B</sub>	Base Current(DC)	0.3	Α
P <sub>C</sub>	Collector Dissipation (T <sub>a</sub> =25°C)	1.2	W
	Collector Dissipation (T <sub>C</sub> =25°C)	20	W
P <sub>C</sub> T <sub>J</sub>	Junction Temperature	150	°C
T <sub>STG</sub>	Storage Temperature	- 55 ~ 150	°C

<sup>\*</sup> PW≤10ms, Duty Cycle≤50%

## **Electrical Characteristics** $T_C=25^{\circ}C$ unless otherwise noted

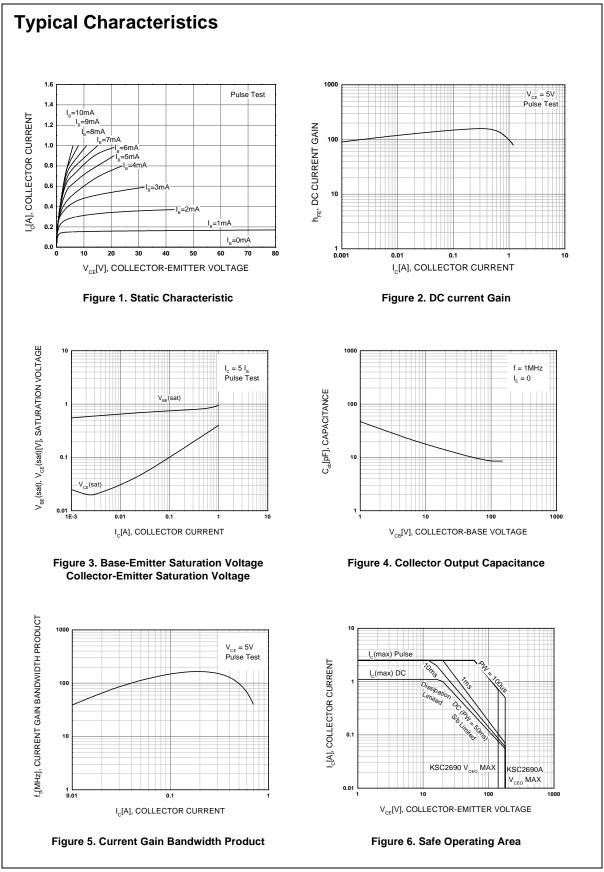
Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
I <sub>CBO</sub>	Collector Cut-off Current	$V_{CB} = 120V, I_{E} = 0$			1	μΑ
I <sub>EBO</sub>	Emitter Cut-off Current	$V_{EB} = 3V, I_{C} = 0$			1	μΑ
h <sub>FE1</sub>	* DC Current Gain	$V_{CE} = 5V$ , $I_C = 5mA$	35	105		
$h_{FE2}$		$V_{CE} = 5V, I_{C} = 0.3A$	60	140	320	
V <sub>CE</sub> (sat)	* Collector-Emitter Saturation Voltage	$I_C = 1A, I_B = 0.2A$		0.4	0.7	V
V <sub>BE</sub> (sat)	* Base-Emitter Saturation Voltage	$I_C = 1A, I_B = 0.2A$		1	1.3	V
f <sub>T</sub>	Current Gain Bandwidth Product	$V_{CE} = 5V, I_{C} = 0.2A$		155		MHz
C <sub>ob</sub>	Output Capacitance	$V_{CB} = 10V, I_{E} = 0, f = 1MHz$		19		pF

<sup>\*</sup> Pulse Test: PW≤350μs, Duty Cycle≤2% Pulsed

## **h**<sub>FE</sub> Classification

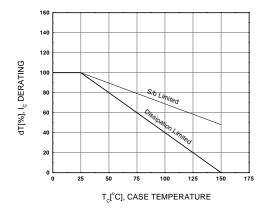
Classification	R	0	Υ
h <sub>FE2</sub>	60 ~ 120	100 ~ 200	160 ~ 320

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# Typical Characteristics (Continued)



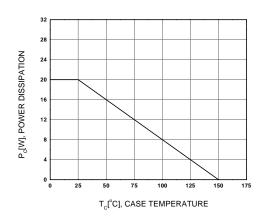


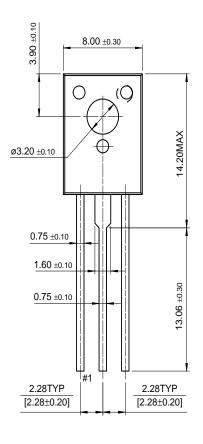
Figure 7. Derating Curve of Safe Operating Areas

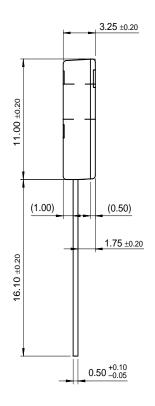
Figure 8. Power Derating

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## **Package Demensions**

TO-126





Dimensions in Millimeters

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